NSN 5961-00-904-7358

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-904-7358 **Inclosure Material:** Glass **Overall Length:** Between 0.170 inches and 0.210 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 70.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 50.00 milliamperes forward current, total rms pascal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: A110a0